



Vincotech

**10-EZ126PA035M7-L859F78T**  
**10-E1126PA035M7-L859F78Z**  
 datasheet

<i>flowPACK E1</i>	1200 V / 35 A
<div style="border: 1px solid black; padding: 5px; margin-bottom: 10px;"> <p style="text-align: center; background-color: #ccc; margin: 0;"><b>Features</b></p> <ul style="list-style-type: none"> <li>IGBT M7 with low <math>V_{CEsat}</math> and improved EMC behavior</li> <li>Standard industrial housing</li> <li>Optimized <math>R_{th(j-s)}</math> with Phase-change Material</li> <li>Built-in NTC</li> </ul> </div> <div style="border: 1px solid black; padding: 5px; margin-bottom: 10px;"> <p style="text-align: center; background-color: #ccc; margin: 0;"><b>Target applications</b></p> <ul style="list-style-type: none"> <li>Industrial Drives</li> </ul> </div> <div style="border: 1px solid black; padding: 5px;"> <p style="text-align: center; background-color: #ccc; margin: 0;"><b>Types</b></p> <ul style="list-style-type: none"> <li>10-EZ126PA035M7-L859F78T</li> <li>10-E1126PA035M7-L859F78Z</li> </ul> </div>	<div style="border: 1px solid black; padding: 5px; margin-bottom: 10px;"> <p style="text-align: center; background-color: #ccc; margin: 0;"><i>flow E1 12 mm housing</i></p> <div style="display: flex; justify-content: space-around; align-items: center;"> </div> <div style="display: flex; justify-content: space-around; margin-top: 5px;"> <span>Press-fit pin</span> <span>Solder Pin</span> </div> </div> <div style="border: 1px solid black; padding: 5px;"> <p style="text-align: center; background-color: #ccc; margin: 0;"><b>Schematic</b></p> </div>

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Inverter Switch</b>				
Collector-emitter voltage	$V_{CES}$		1200	V
Collector current	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	49	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	70	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	108	W
Gate-emitter voltage	$V_{GES}$		±20	V
Maximum junction temperature	$T_{jmax}$		175	°C



## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
<b>Inverter Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		1200	V
Continuous (direct) forward current	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	41	A
Repetitive peak forward current	$I_{FRM}$		70	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	78	W
Maximum junction temperature	$T_{jmax}$		175	°C

## Module Properties

### Thermal Properties

Storage temperature	$T_{stg}$		-40...+125	°C
Operation temperature under switching condition	$T_{jop}$		-40...( $T_{jmax} - 25$ )	°C

### Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
		AC Voltage $t_p = 1\text{ min}$	2500	V
Creepage distance			min. 12,7	mm
Clearance			8,62	mm
Comparative Tracking Index	CTI		≥ 600	

\*100 % tested in production



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## Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		$V_{GS}$ [V]	$V_{GE}$ [V]	$V_{DS}$ [V]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Inverter Switch

#### Static

Parameter	Symbol	$V_{GS}$ [V]	$V_{GE}$ [V]	$V_{DS}$ [V]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max	Unit
Gate-emitter threshold voltage	$V_{GE(th)}$		10		0,0035	25	5,4	6,0	6,6	V
Collector-emitter saturation voltage	$V_{CESat}$	15			35	25 125 150		1,48 1,64 1,68	1,85	V
Collector-emitter cut-off current	$I_{CES}$	0		1200		25			80	μA
Gate-emitter leakage current	$I_{GES}$	20	0			25			500	nA
Internal gate resistance	$r_g$							none		Ω
Input capacitance	$C_{ies}$							7900		pF
Output capacitance	$C_{oes}$	0	10			25		270		
Reverse transfer capacitance	$C_{res}$							97		
Gate charge	$Q_g$	15		600	35	25		260		nC

#### Thermal

Parameter	Symbol	Value	Unit
Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)	K/W

#### Dynamic

Parameter	Symbol	$V_{GS}$ [V]	$V_{GE}$ [V]	$V_{DS}$ [V]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max	Unit
Turn-on delay time	$t_{d(on)}$					25 125 150		223 240 233		ns
Rise time	$t_r$					25 125 150		28 34 35		
Turn-off delay time	$t_{d(off)}$					25 125 150		227 252 259		
Fall time	$t_f$					25 125 150		97 114 123		
Turn-on energy (per pulse)*	$E_{on}$					25 125 150		2,45 3,23 3,44		mWs
Turn-off energy (per pulse)*	$E_{off}$					25 125 150		2,46 3,24 3,46		

\*  $L_s = 14$  nH



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## Characteristic Values

Parameter	Symbol	Conditions					Value			Unit
		$V_{GE}$ [V]	$V_{CE}$ [V]	$I_C$ [A]	$T_j$ [°C]	Min	Typ	Max		

### Inverter Diode

#### Static

Parameter	Symbol	$V_{GS}$ [V]	$V_{DS}$ [V]	$I_D$ [A]	$T_j$ [°C]	Min	Typ	Max	Unit
Forward voltage	$V_F$			35	25 125 150		1,66 1,76 1,75	2,1	V
Reverse leakage current	$I_R$		1200		25			40	μA

#### Thermal

Parameter	Symbol	Conditions	Value	Unit
Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)	1,22	K/W

#### Dynamic

Parameter	Symbol	$dI/dt$	$I_D$ [A]	$T_j$ [°C]	Value	Unit	
Peak recovery current	$I_{RRM}$			25 125 150	41 40 41	A	
Reverse recovery time	$t_{rr}$			25 125 150	267 425 450	ns	
Recovered charge	$Q_r$	$dI/dt = 1364$ A/μs $dI/dt = 1192$ A/μs $dI/dt = 1157$ A/μs	±15	600	35	3,80 5,84 6,39	μC
Reverse recovered energy	$E_{rec}$			25 125 150	1,48 2,39 2,60	mWs	
Peak rate of fall of recovery current	$(di_{ri}/dt)_{max}$			25 125 150	485 353 343	A/μs	

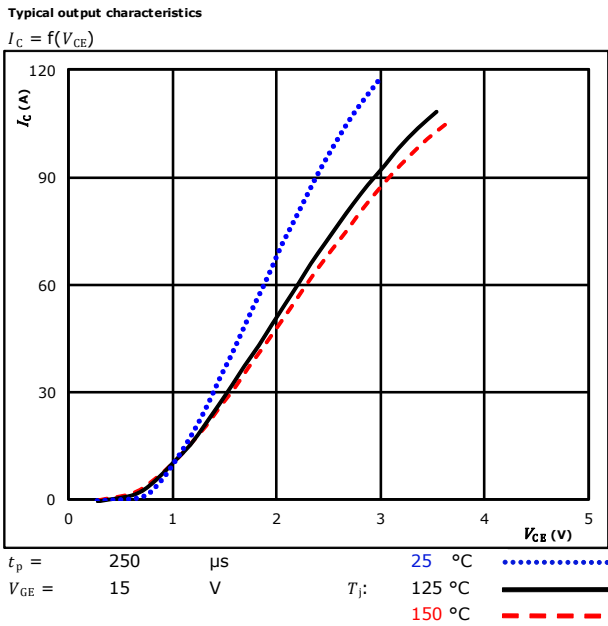
### Thermistor

Parameter	Symbol	Conditions	Value	Unit
Rated resistance	$R$		25	5 kΩ
Deviation of $R_{100}$	$\Delta_{R/R}$	$R_{100} = 493 \Omega$	100	-5 +5 %
Power dissipation	$P$		25	245 mW
Power dissipation constant			25	1,4 mW/K
B-value	$B_{(25/50)}$	Tol. ±2 %	25	3375 K
B-value	$B_{(25/100)}$	Tol. ±2 %	25	3437 K
Vincotech NTC Reference				K

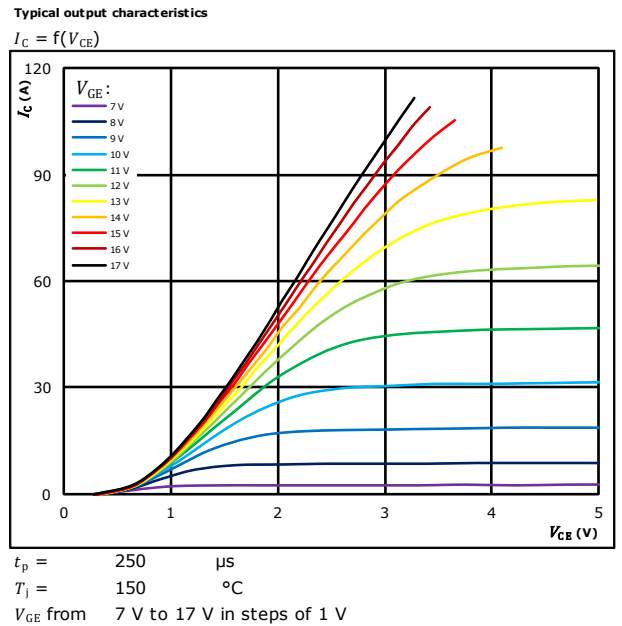


## Inverter Switch Characteristics

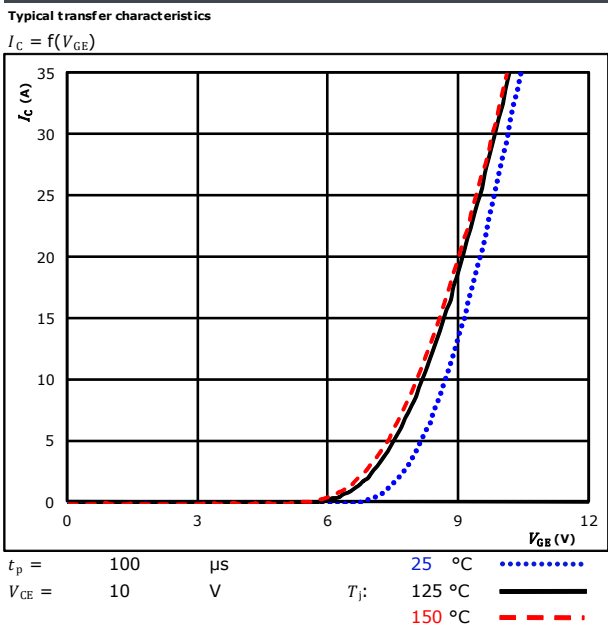
**figure 1.** IGBT



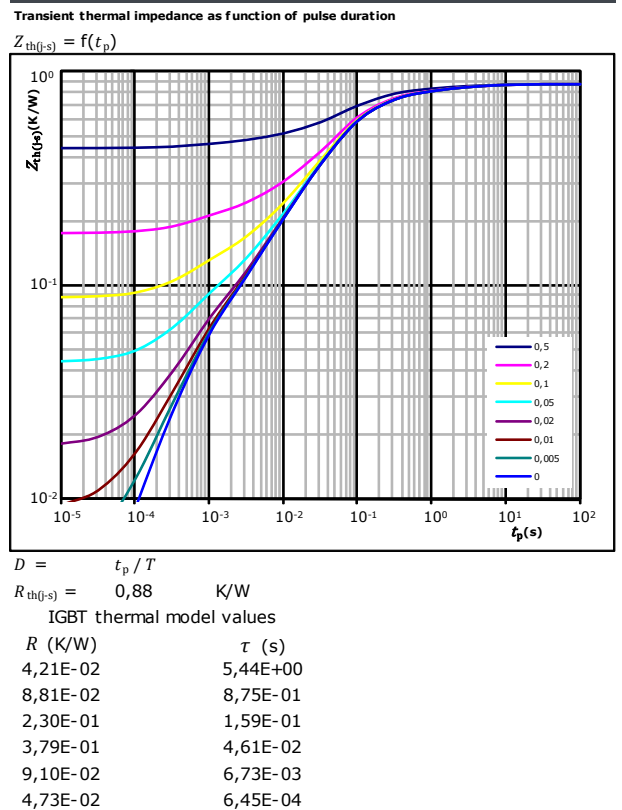
**figure 2.** IGBT



**figure 3.** IGBT



**figure 4.** IGBT





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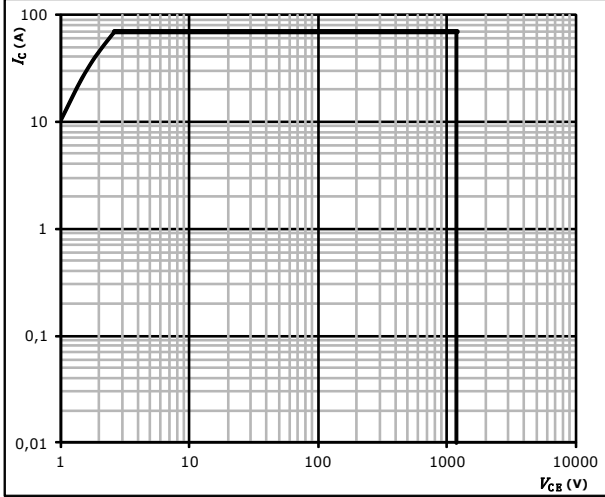
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## Inverter Switch Characteristics

figure 5. IGBT

Safe operating area

$$I_C = f(V_{CE})$$



$D =$  single pulse  
 $T_s =$  80 °C  
 $V_{GE} =$  ±15 V  
 $T_j =$   $T_{jmax}$

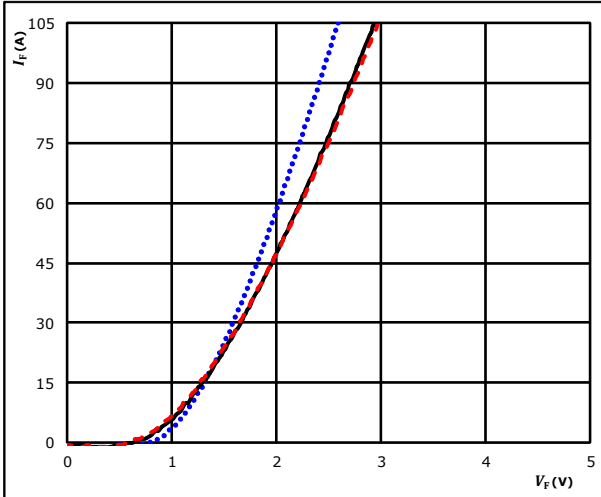


## Inverter Diode Characteristics

**figure 1.** **FWD**

Typical forward characteristics

$$I_F = f(V_F)$$

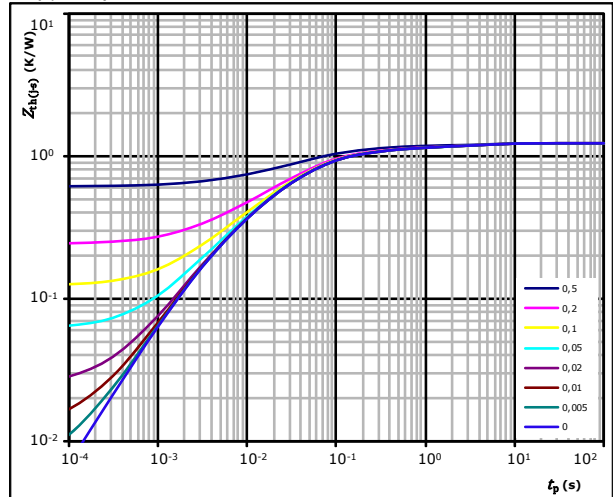


$t_p = 250 \mu s$        $T_j$ : 25 °C .....  
 125 °C ———  
 150 °C - - - -

**figure 2.** **FWD**

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 1,22 \text{ K/W}$   
 FWD thermal model values

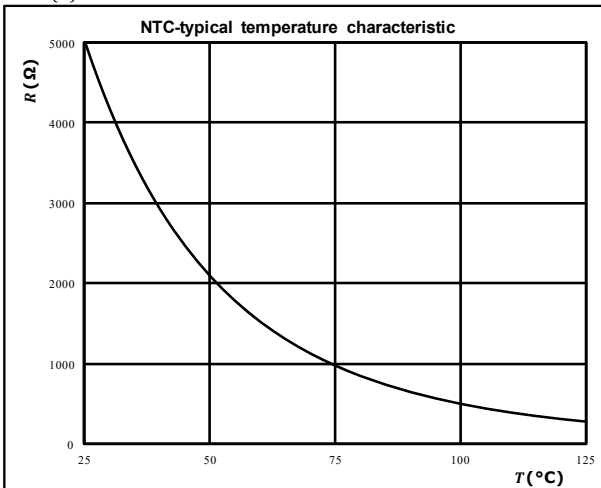
$R$ (K/W)	$\tau$ (s)
1,07E-01	3,56E+00
1,60E-01	2,77E-01
5,76E-01	5,00E-02
2,75E-01	1,24E-02
1,01E-01	2,87E-03

## Thermistor Characteristics

**figure 1.** **Thermistor**

Typical NTC characteristic  
 as a function of temperature

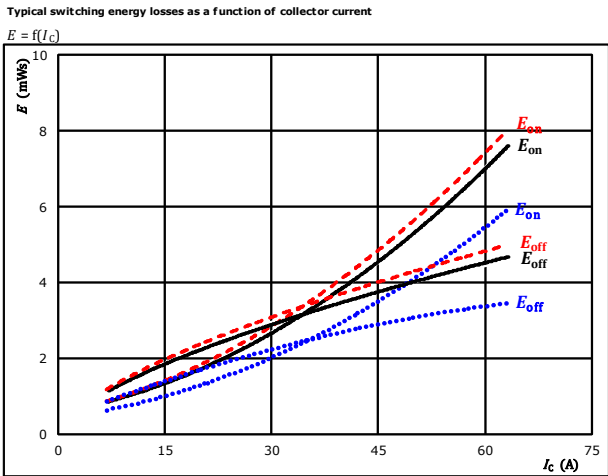
$$R = f(T)$$





## Inverter Switching Characteristics

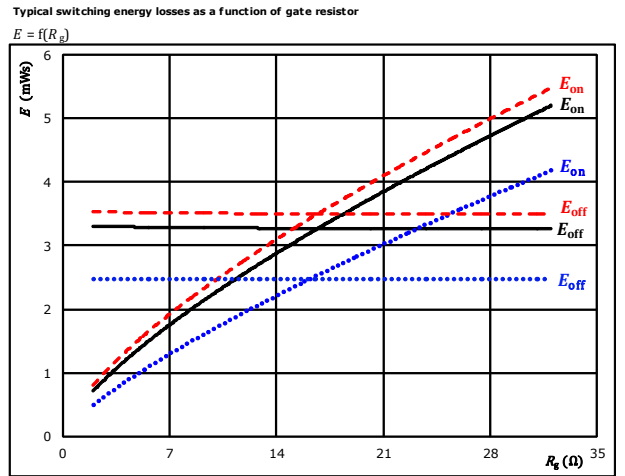
**figure 1.** IGBT



With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{g(on)} = 16$   $\Omega$   
 $R_{g(off)} = 16$   $\Omega$

$T_j$ : 25 °C (dotted blue)  
 125 °C (solid black)  
 150 °C (dashed red)

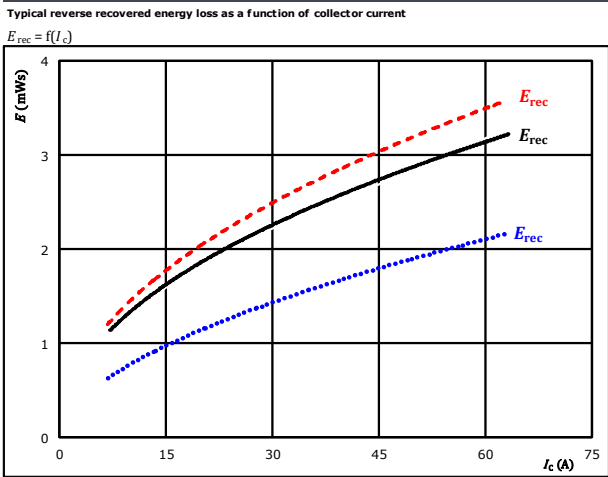
**figure 2.** IGBT



With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_C = 35$  A

$T_j$ : 25 °C (dotted blue)  
 125 °C (solid black)  
 150 °C (dashed red)

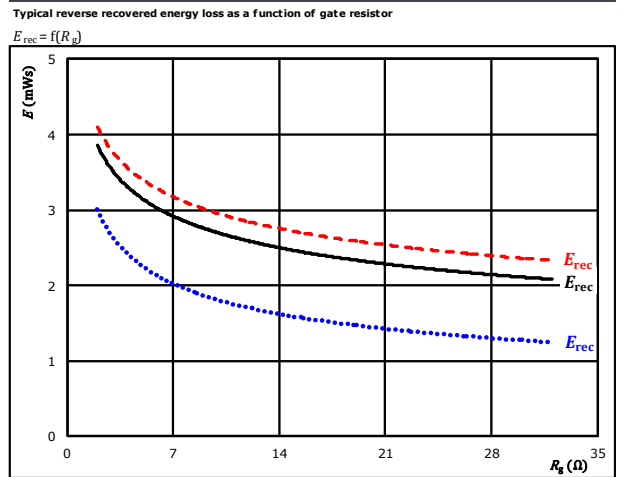
**figure 3.** FWD



With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $R_{g(on)} = 16$   $\Omega$

$T_j$ : 25 °C (dotted blue)  
 125 °C (solid black)  
 150 °C (dashed red)

**figure 4.** FWD



With an inductive load at  
 $V_{CE} = 600$  V  
 $V_{GE} = \pm 15$  V  
 $I_C = 35$  A

$T_j$ : 25 °C (dotted blue)  
 125 °C (solid black)  
 150 °C (dashed red)



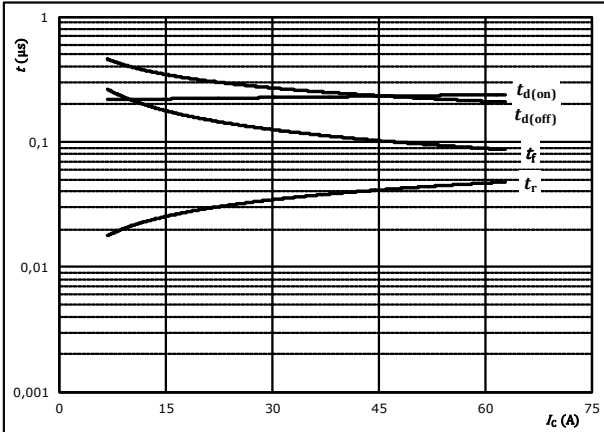


## Inverter Switching Characteristics

**figure 5.** IGBT

Typical switching times as a function of collector current

$$t = f(I_C)$$



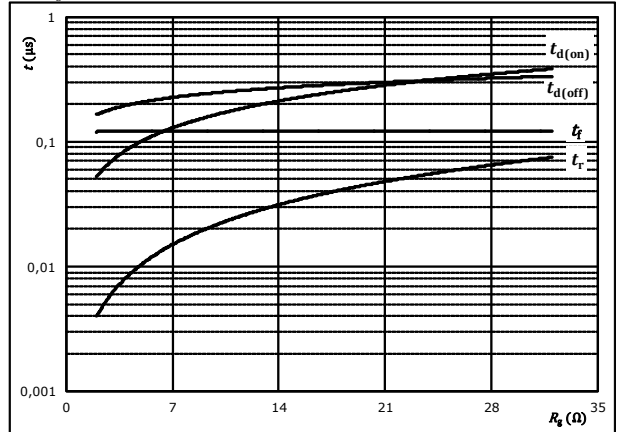
With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$R_{g(on)} =$	16	Ω
$R_{g(off)} =$	16	Ω

**figure 6.** IGBT

Typical switching times as a function of gate resistor

$$t = f(R_g)$$



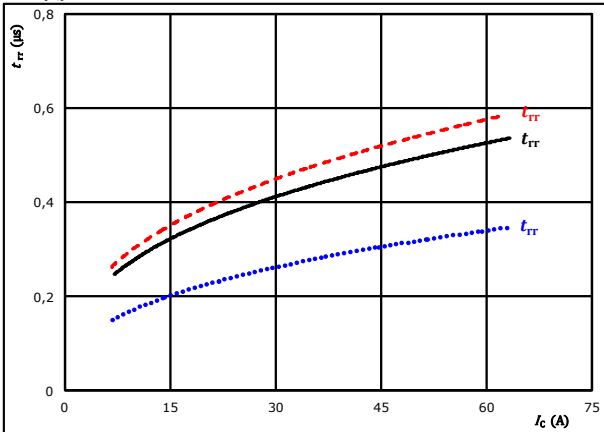
With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$I_C =$	35	A

**figure 7.** FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_C)$$

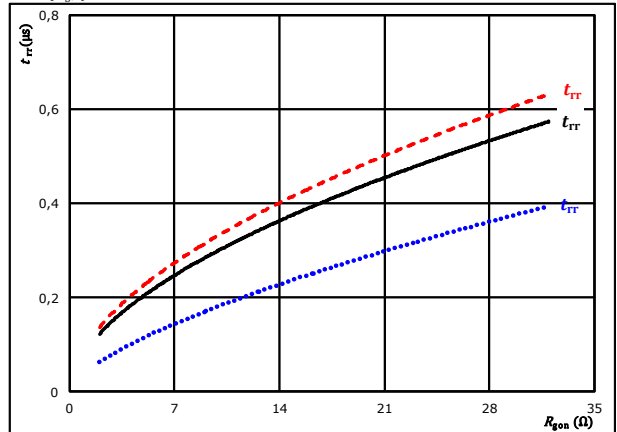


At	$V_{CE} =$	600	V	$T_j:$	25 °C	.....
	$V_{GE} =$	±15	V		125 °C	————
	$R_{g(on)} =$	16	Ω		150 °C	- - - -

**figure 8.** FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

$$t_{rr} = f(R_{g(on)})$$

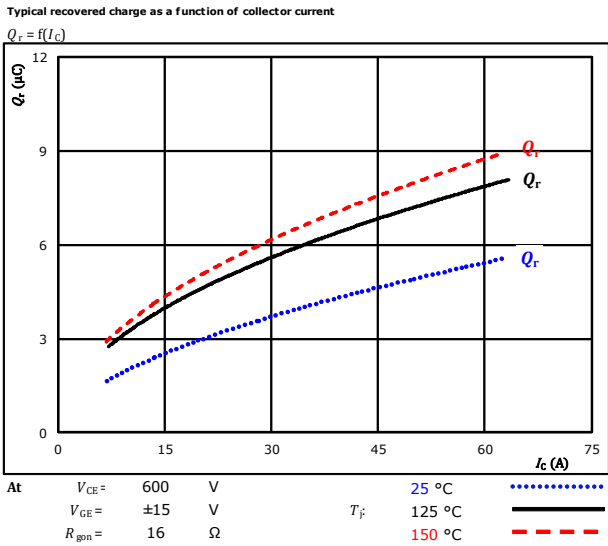


At	$V_{CE} =$	600	V	$T_j:$	25 °C	.....
	$V_{GE} =$	±15	V		125 °C	————
	$I_C =$	35	A		150 °C	- - - -

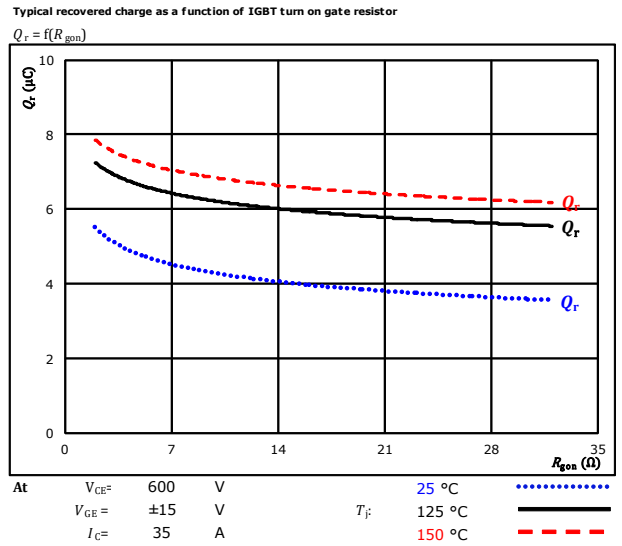


## Inverter Switching Characteristics

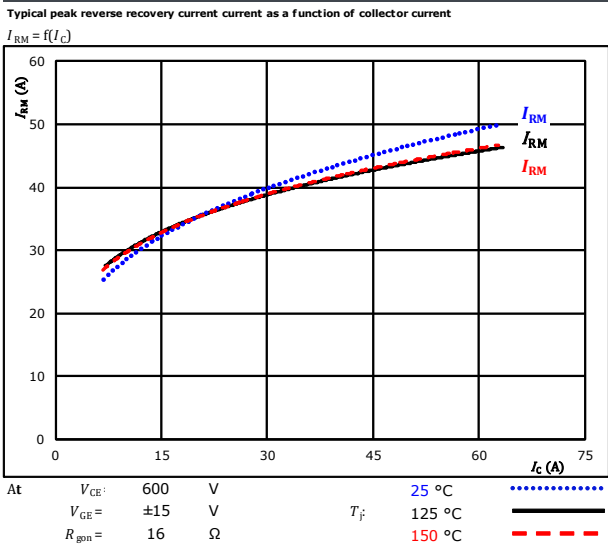
**figure 9.** FWD



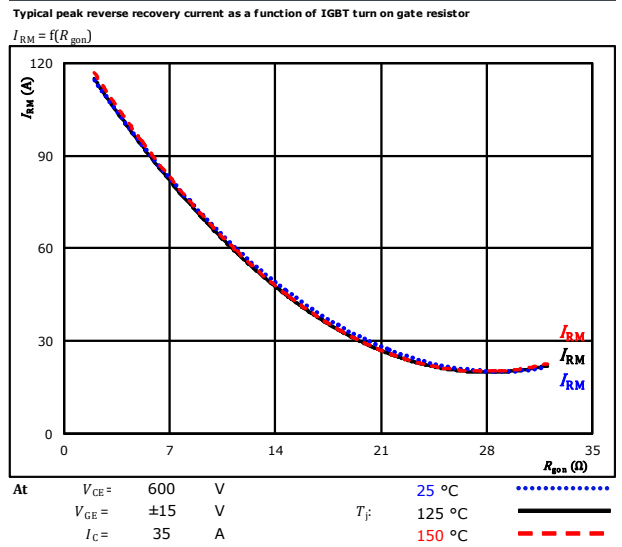
**figure 10.** FWD



**figure 11.** FWD



**figure 12.** FWD



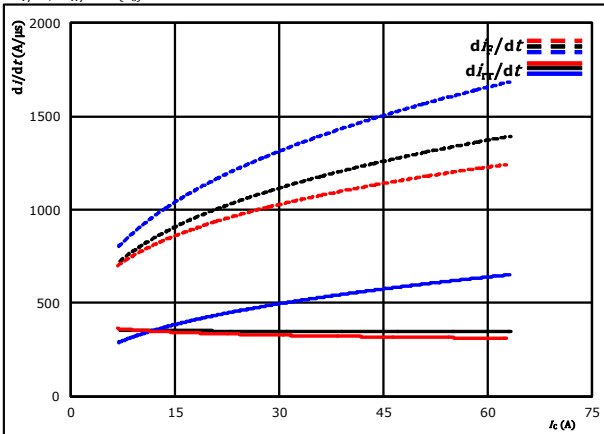


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## Inverter Switching Characteristics

**figure 13.** FWD

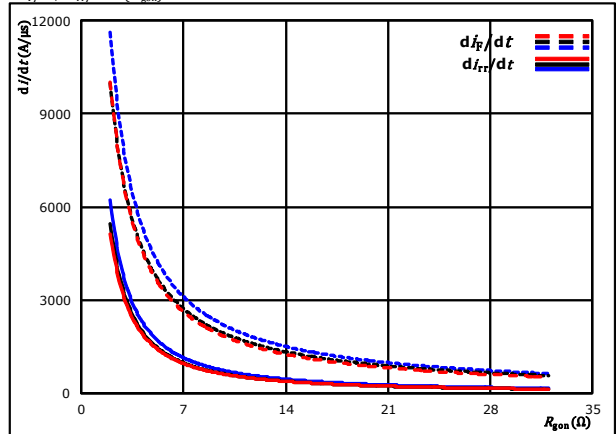
Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_{rr}/dt = f(I_c)$



At  $V_{CE} = 600$  V  $T_j = 25$  °C  
 $V_{GE} = \pm 15$  V  $T_j = 125$  °C  
 $R_{gon} = 16$  Ω  $T_j = 150$  °C

**figure 14.** FWD

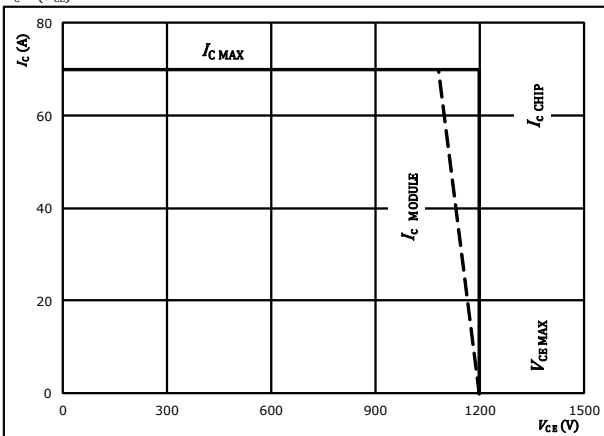
Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor  
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



At  $V_{CE} = 600$  V  $T_j = 25$  °C  
 $V_{GE} = \pm 15$  V  $T_j = 125$  °C  
 $I_c = 35$  A  $T_j = 150$  °C

**figure 15.** IGBT

Reverse bias safe operating area  
 $I_c = f(V_{CB})$



At  $T_j = 175$  °C  
 $R_{gon} = 16$  Ω  
 $R_{goff} = 16$  Ω



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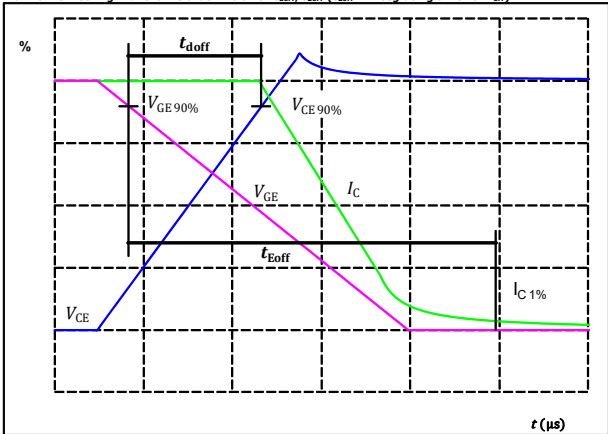
## Inverter Switching Definitions

**General conditions**

$T_j$	=	125 °C
$R_{gon}$	=	16 $\Omega$
$R_{goff}$	=	16 $\Omega$

**figure 1.** IGBT

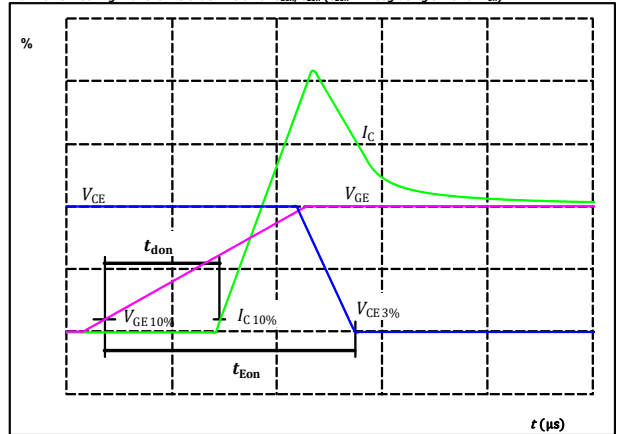
Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )



$V_{CE}(0\%) =$	-15	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	600	V
$I_C(100\%) =$	35	A
$t_{doff} =$	252	ns

**figure 2.** IGBT

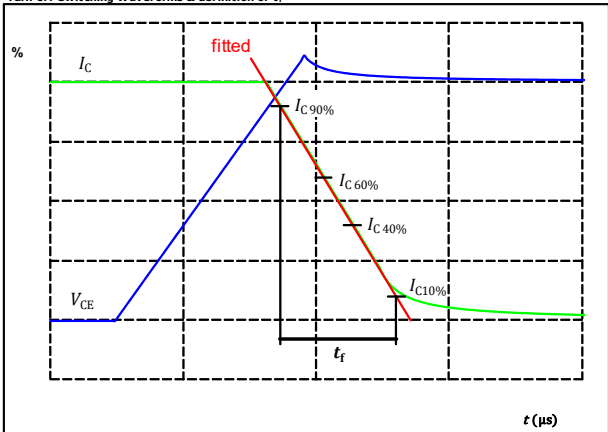
Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )



$V_{CE}(0\%) =$	-15	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	600	V
$I_C(100\%) =$	35	A
$t_{don} =$	240	ns

**figure 3.** IGBT

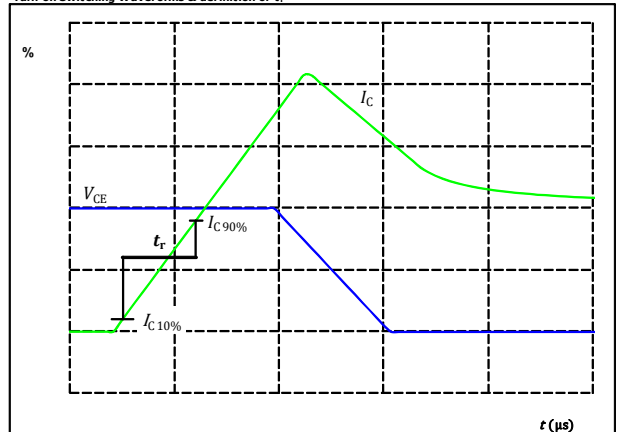
Turn-off Switching Waveforms & definition of  $t_f$



$V_C(100\%) =$	600	V
$I_C(100\%) =$	35	A
$t_f =$	114	ns

**figure 4.** IGBT

Turn-on Switching Waveforms & definition of  $t_r$



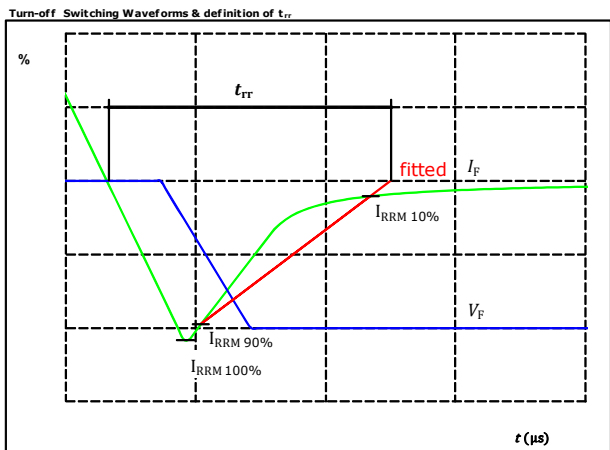
$V_C(100\%) =$	600	V
$I_C(100\%) =$	35	A
$t_r =$	34	ns



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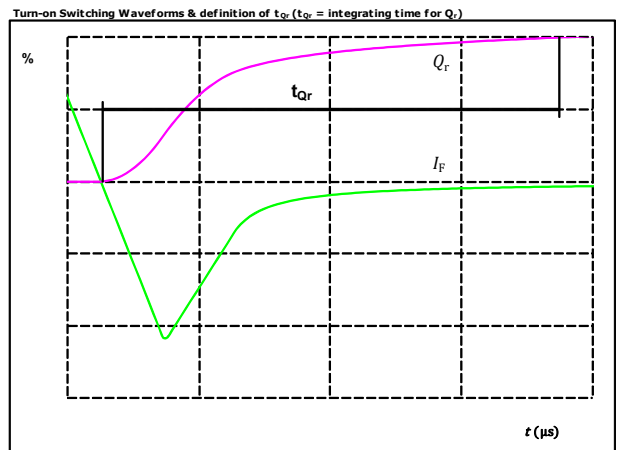
## Inverter Switching Characteristics

**figure 5.** FWD



$V_F(100\%) =$	600	V
$I_F(100\%) =$	35	A
$I_{RRM}(100\%) =$	40	A
$t_{rr} =$	425	ns

**figure 6.** FWD



$I_F(100\%) =$	35	A
$Q_r(100\%) =$	5,84	$\mu\text{C}$



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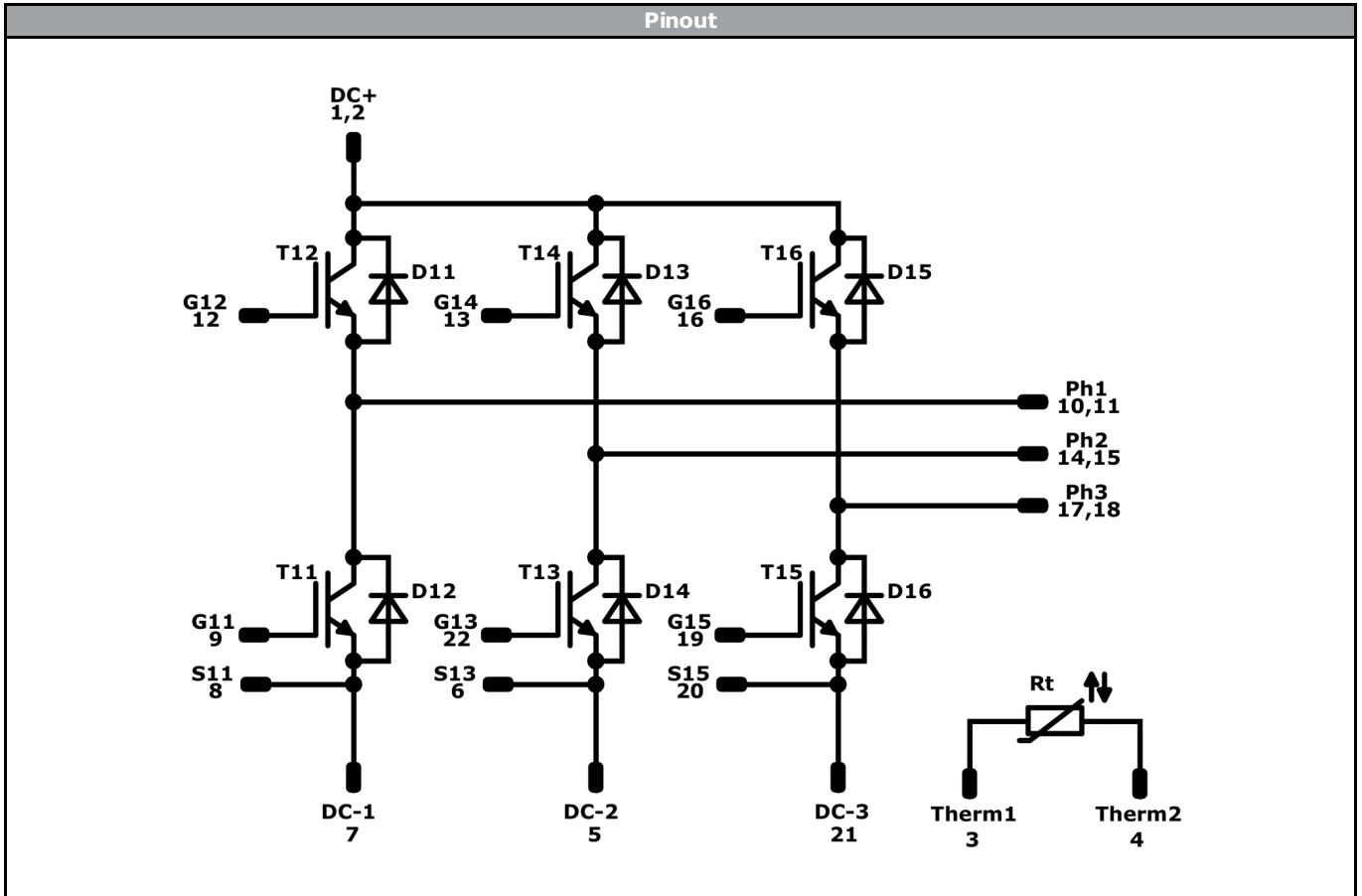
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Ordering Code & Marking								
Version			Ordering Code					
without thermal paste 12 mm housing with press-fit pins			10-EZ126PA035M7-L859F78T					
with thermal paste 12 mm housing with press-fit pins			10-EZ126PA035M7-L859F78T-/3/					
without thermal paste 12 mm housing with Solder pins			10-E1126PA035M7-L859F78Z					
with thermal paste 12 mm housing with Solder pins			10-E1126PA035M7-L859F78Z-/3/					
NN-NNNNNNNNNNNN TTTTWW WWYY UL VIN LLLL SSSS			<b>Text</b>	<b>Name</b>	<b>Date code</b>	<b>UL &amp; VIN</b>	<b>Lot</b>	<b>Serial</b>
				NN-NNNNNNNNNNNN-TTTTWW	WWYY	UL VIN	LLLLL	SSSS
			<b>Datamatrix</b>	<b>Type&amp;Ver</b>	<b>Lot number</b>	<b>Serial</b>	<b>Date code</b>	
			TTTTTWW	LLLLL	SSSS	WWYY		

Pin table				Outline	
Pin	X	Y	Function		
1	12,8	9,6	DC+	<p>Solder pin: <math>\square 0,64 \pm 0,03</math>, <math>13,9 \pm 0,1</math>, <math>16,4 \pm 0,5</math></p> <p>Press-fit pin: center of press-fit pinhead for connection parameter see the handling instruction, <math>13,08 \pm 0,1</math>, <math>16,4 \pm 0,5</math></p> <p>Pin positions: <math>\pm 0,4\text{mm}</math> at the end of pins. Dimension of coordinate axis is only offset without tolerance.</p>	
2	16	9,6	DC+		
3	22,4	9,6	Therm1		
4	25,6	9,6	Therm2		
5	32	9,6	DC-2		
6	32	6,4	S13		
7	32	3,2	DC-1		
8	32	0	S11		
9	28,8	0	G11		
10	6,4	0	Ph1		
11	3,2	0	Ph1		
12	0	0	G12		
13	0	6,4	G14		
14	0	16	Ph2		
15	0	19,2	Ph2		
16	0	25,6	G16		
17	3,2	25,6	Ph3		
18	6,4	25,6	Ph3		
19	28,8	25,6	G15		
20	32	25,6	S15		
21	32	22,4	DC-3		
22	32	16	G13		



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<b>Identification</b>					
<b>ID</b>	<b>Component</b>	<b>Voltage</b>	<b>Current</b>	<b>Function</b>	<b>Comment</b>
T11, T12, T13, T14, T15, T16	IGBT	1200 V	35 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	35 A	Inverter Diode	
Rt	NTC			Thermistor	




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10-EZ126PA035M7-L859F78T  
10-E1126PA035M7-L859F78Z  
datasheet

Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction
Handling instructions for <i>flow</i> E1 packages see vincotech.com website.

Package data
Package data for <i>flow</i> E1 packages see vincotech.com website.

UL recognition and file number
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. 

Document No.:	Date:	Modification:	Pages
10-Ex126PA035M7-L859F78x-D4-14	27 May. 2019	Outline updated	14

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
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